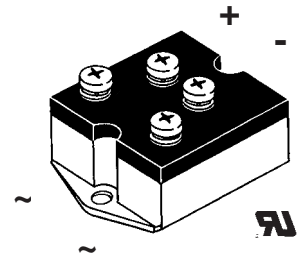
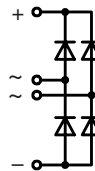


# Single Phase Rectifier Bridge

$I_{dAVM} = 50 \text{ A}$   
 $V_{RRM} = 800-1800 \text{ V}$

$V_{RSM}$ V	$V_{RRM}$ V	Type
800	800	VBO 50-08NO7
1200	1200	VBO 50-12NO7
1400	1400	VBO 50-14NO7
1600	1600	VBO 50-16NO7
1800	1800	VBO 50-18NO7*

\* delivery time on request



Symbol	Conditions	Maximum Ratings
$I_{dAVM}$	$T_C = 64^\circ\text{C}$ , module	50 A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	t = 10 ms (50 Hz), sine 750 A t = 8.3 ms (60 Hz), sine 820 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	t = 10 ms (50 Hz), sine 670 A t = 8.3 ms (60 Hz), sine 740 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	t = 10 ms (50 Hz), sine 2800 A <sup>2</sup> s t = 8.3 ms (60 Hz), sine 2820 A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$ $V_R = 0$	t = 10 ms (50 Hz), sine 2250 A <sup>2</sup> s t = 8.3 ms (60 Hz), sine 2300 A <sup>2</sup> s
$T_{VJ}$		-40...+150 °C
$T_{VJM}$		150 °C
$T_{stg}$		-40...+150 °C
$V_{ISOL}$	50/60 Hz, RMS	t = 1 min 2500 V~ t = 1 s 3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$	
$M_d$	Mounting torque (M5)	5 ±15% Nm 44 ±15% lb.in.
	Terminal connection torque (M5)	3 ±15% Nm 26 ±15% lb.in.
Weight	typ.	260 g

### Features

- Package with screw terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

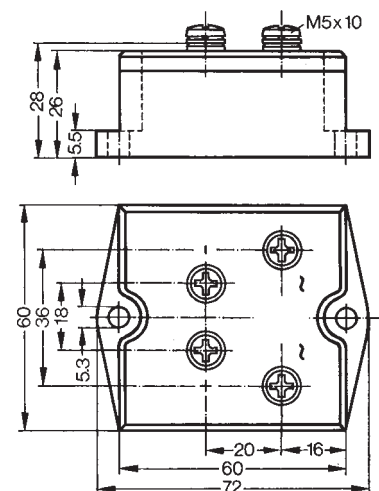
### Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

### Dimensions in mm (1 mm = 0.0394")



Symbol	Conditions	Characteristic Values
$I_R$	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$ ; $T_{VJ} = T_{VJM}$	$\leq 10.0 \text{ mA}$
$V_F$	$I_F = 150 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$	$\leq 1.6 \text{ V}$
$V_{T0}$	For power-loss calculations only	0.85 V
$r_T$	$T_{VJ} = T_{VJM}$	8 mΩ
$R_{thJC}$	per diode; DC current	2.6 KW
	per module	0.65 KW
$R_{thJK}$	per diode; DC current	2.84 KW
	per module	0.71 KW

Data according to IEC 60747 refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

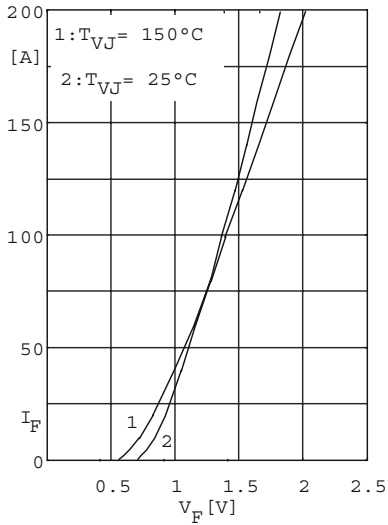


Fig. 1 Forward current versus voltage drop per diode

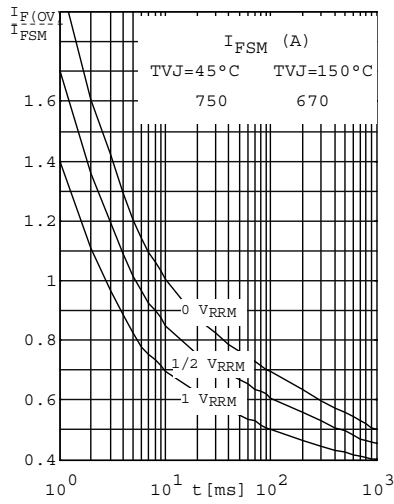


Fig. 2 Surge overload current per diode  
 $I_{FSM}$ : Crest value. t: duration

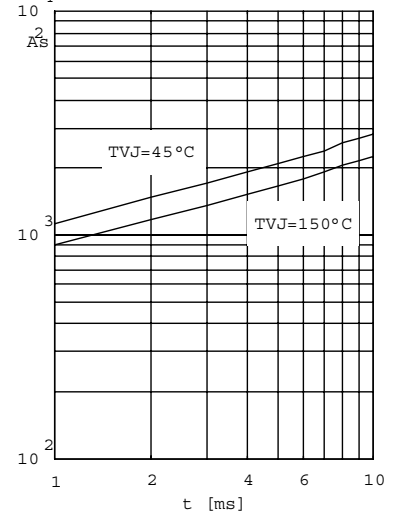


Fig. 3  $\int i^2 dt$  versus time (1-10ms) per diode or thyristor

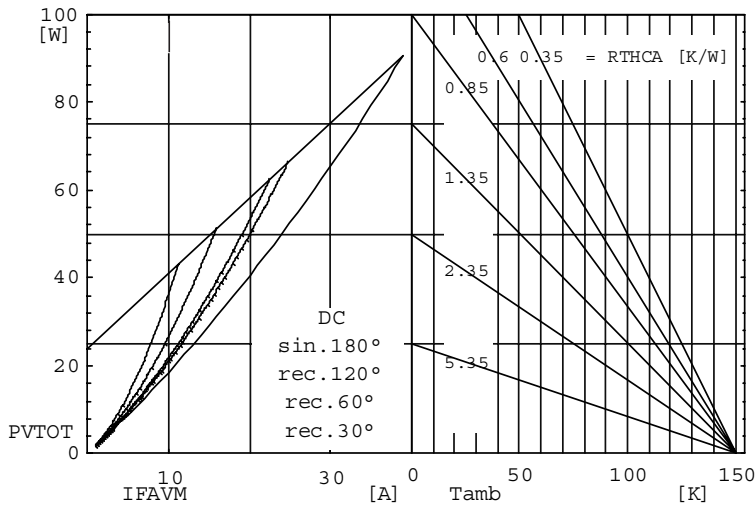


Fig. 4 Power dissipation versus direct output current and ambient temperature

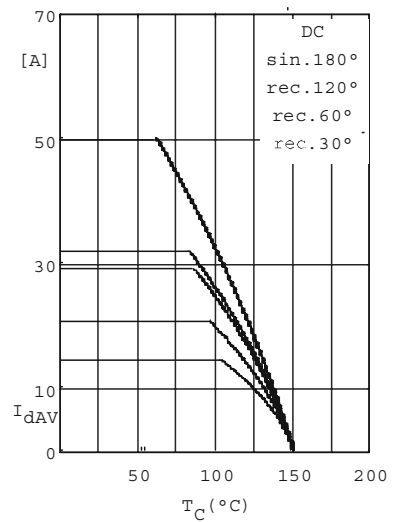


Fig.5 Maximum forward current at case temperature

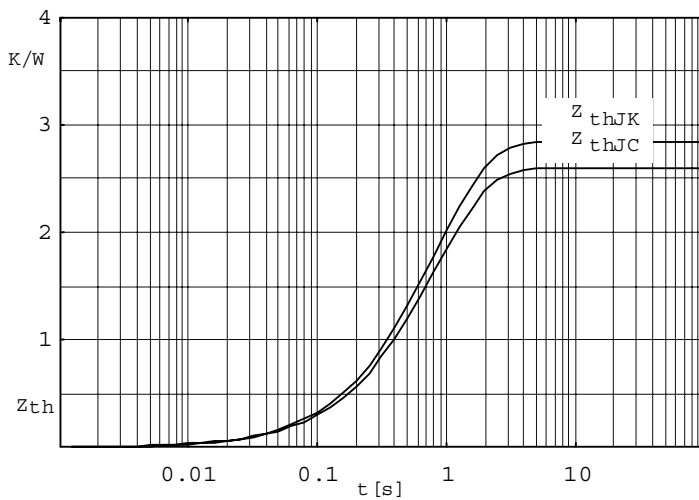


Fig. 6 Transient thermal impedance per diode or thyristor, calculated